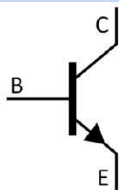


SOT-23 NPN Silicon NPN transistor in a SOT-23 Plastic Package.

2SB710(A)
 Complementary pair with 2SB710(A)

General power amplifier applications.

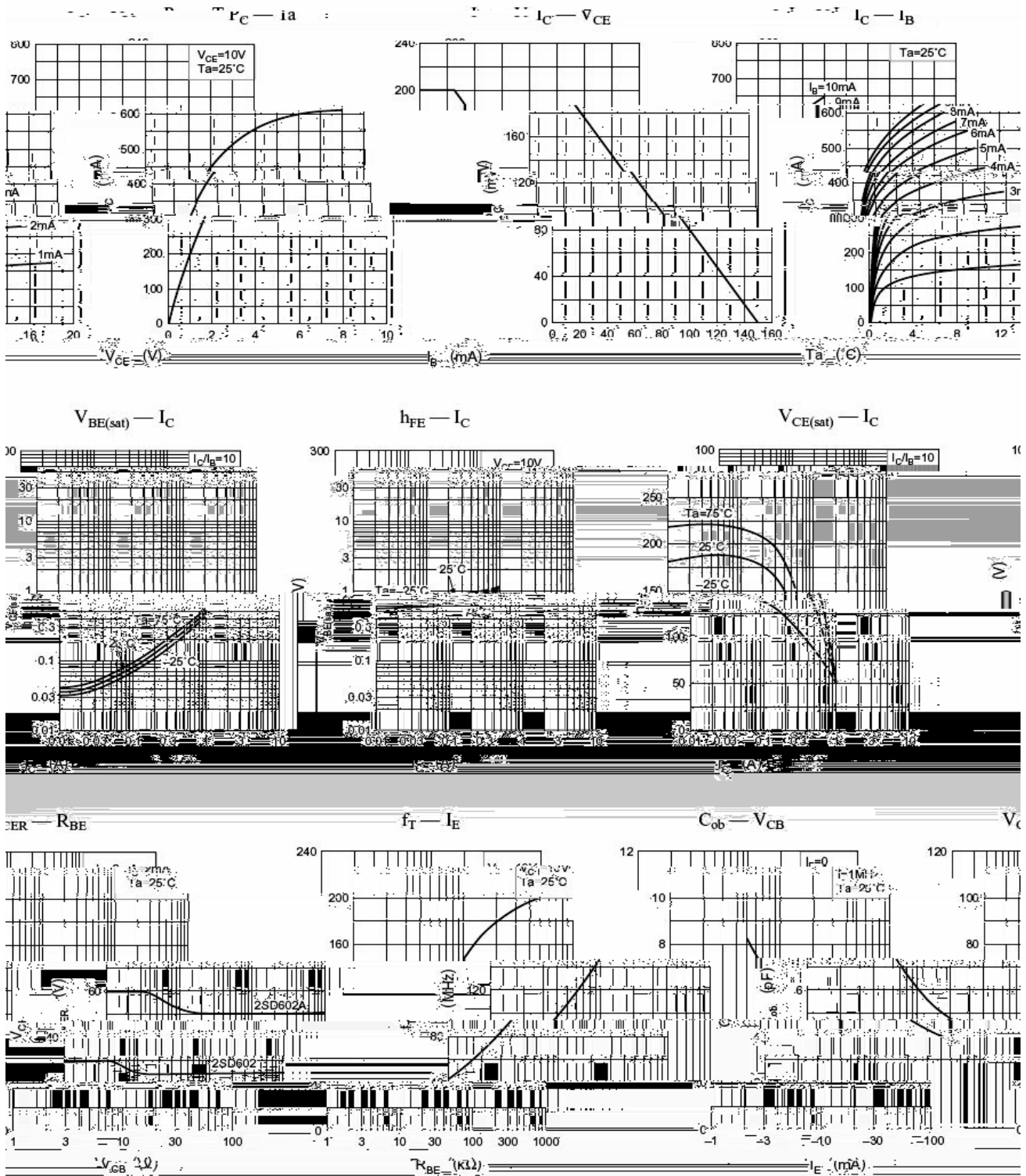


PIN1 Base PIN 2 Emitter PIN 3 Collector

h _{FE} Classifications Symbol		Q	R	S
h _{FE} Range		85-170	120-240	170-340
Marking	2SD602 2SD602A	H2WQ H2XQ	H2WR H2XR	H2WS H2XS

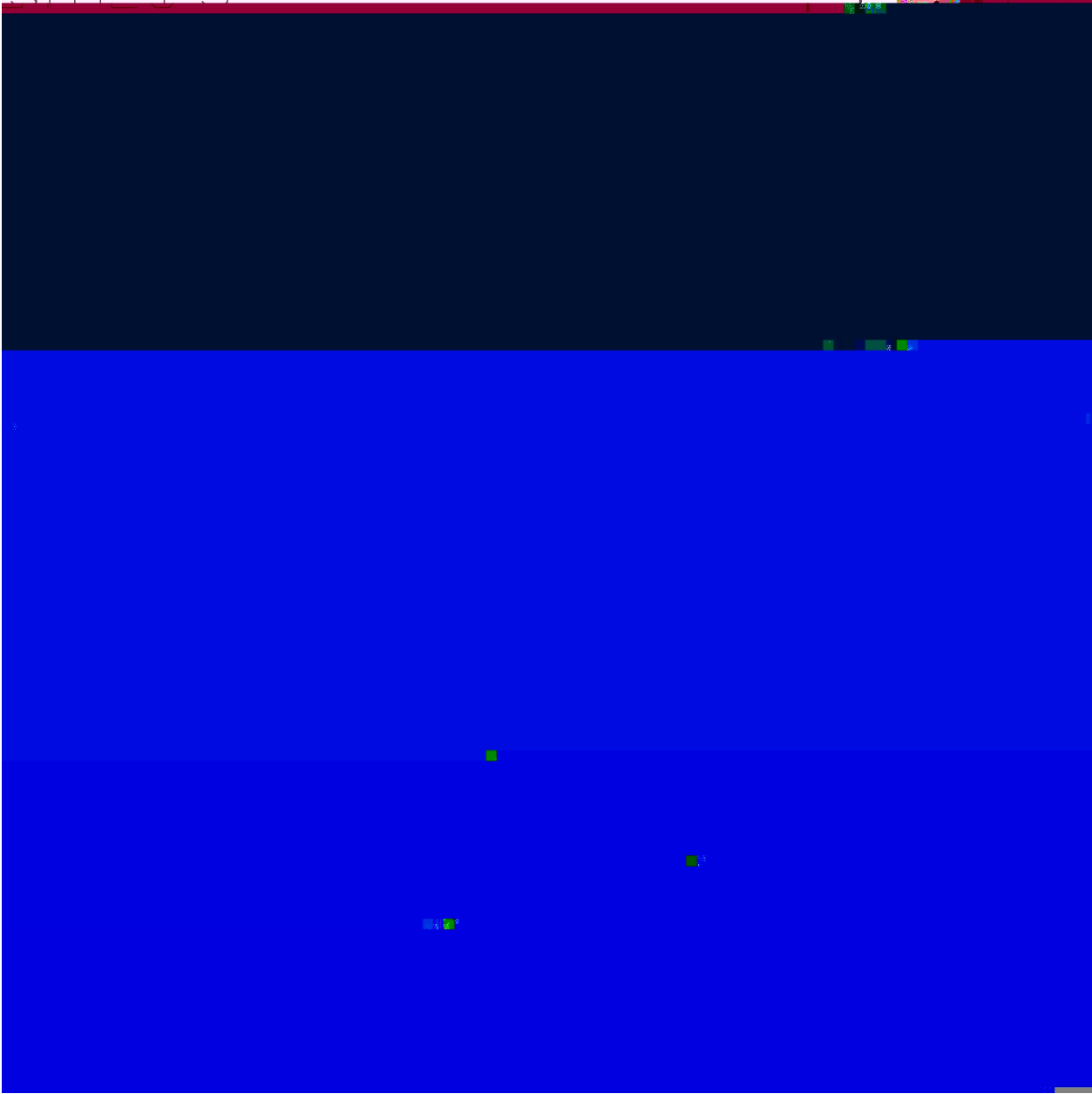
Parameter		Symbol	Rating	Unit
Collector to Base Voltage	2SD602 2SD602A	V_{CBO}	30 60	V
Collector to Emitter Voltage	2SD602 2SD602A	V_{CEO}	25 50	V
Emitter to Base Voltage		V_{EBO}	5.0	V
Collector Current		I_C	500	mA
Collector Current(pulse)		I_{CP}	1.0	A
Collector Power Dissipation		P_C	200	mW
Junction Temperature		T_j	150	°C
Storage Temperature Range		T_{stg}	-55 150	°C

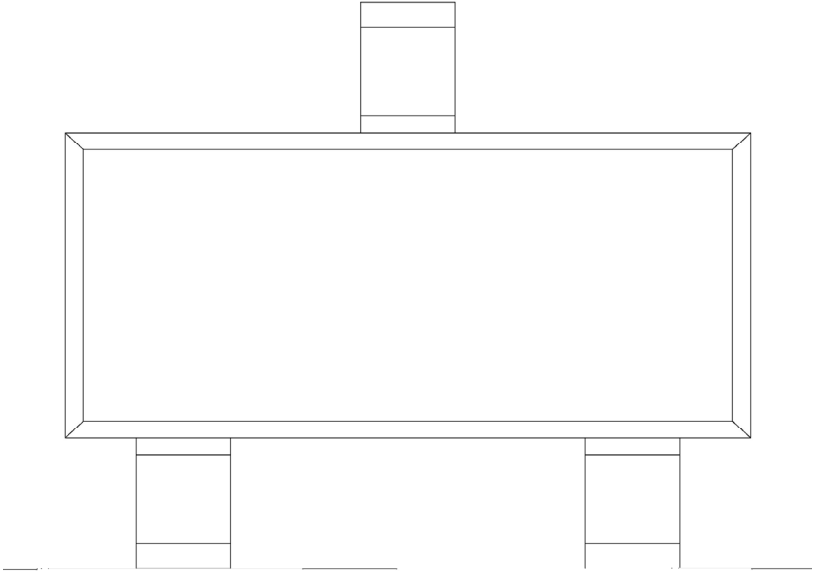
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	I_{CBO}	$V_{CB}=20V$ $I_E=0$			0.1	μA
Collector-Base Breakdown Voltage	V_{CBO}	2SD602 2SD602A $I_C=10$				



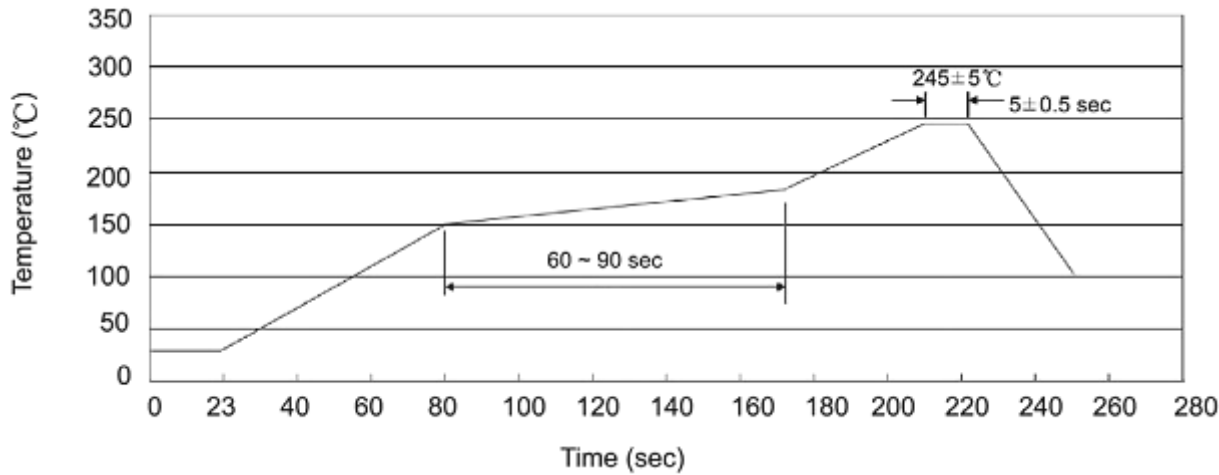
SOT-23

单位





Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-------|-----|----|-----------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245±5 | | | 5±0.5sec; | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

260±5 10±1 sec. Temp.:260±5℃ Time:10±1 sec

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-23	3,000	10	30,000	6	180,000	7 ×8	180×120×180	390×385×205